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## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China













#### 3A, 1.25MHZ HIGH PERFORMANCE SYNCHRONOUS BUCK CONVERTER

### **Description**

The AP3436/A is a step-down DC-DC converter with integrated power stage capable of driving up to 3A continuous output current. It integrates 2 N-channel power MOSFETs with low on-resistance. Current mode control provides fast transient response and cycle-by-cycle current limit.

For AP3436, the regulator adopts current-mode in forced pulse-width modulation (PWM) mode with 1.25MHz switching frequency internally, which allows small-sized components, such as capacitors and inductors. This feature greatly simplifies the design of switch-mode power supplies. Under PWM mode, the device remains at the fixed PWM operation (typical at 1.25MHz), regardless of if the load current is high or low.

For AP3436A, the regulator operates in either fixed PWM mode or a pulse-skipping modulation (PSM) mode depending on the different load conditions. The device can operate at typical 1.25MHz fixed switching frequency under heavy load condition. At light load, the regulator enters a PSM mode to minimize the switching loss by reducing the switching frequency.

The AP3436/A provides EN function. Pulling this pin high statically enables the device while pulling the pin low statically for longer than 10µs will shut it down.

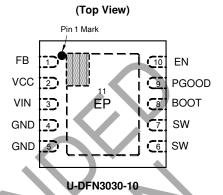
Under Voltage Lockout is internally set at 2.75V for  $V_{CC}$  detection. The output voltage startup ramp is controlled by the soft start. An open drain power good signal indicates the output is within 75% to 125% of its nominal voltage.

The AP3436/A is available in U-DFN3030-10 package.

## **Applications**

- Desktop & Notebook
- Low Voltage, High Density Power System
- Consumer Application Such as Set Top Box, LCD Display and CPE Equipment

### **Pin Assignments**



### **Features**

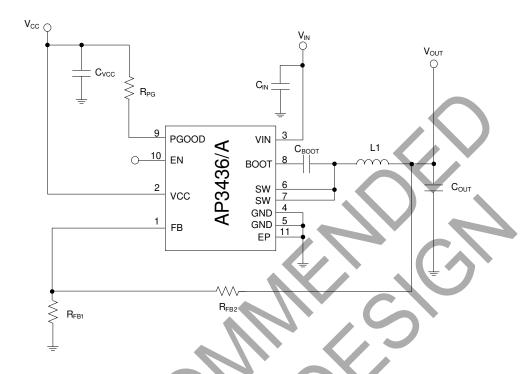
- Analog Power Input V<sub>CC</sub> Range: 3.0V to 5.5V
- Power Input V<sub>IN</sub> Range: 1.3V to 5.5V
- 0.6V Reference Voltage with ±1.5% Precision
- 2 MOSFETs (Typ 50mΩ) for High Efficiency at 3A Loads
- High Efficiency: Up to 95%
- Output Current: 3A
- Current Mode Control
- Built-in Soft Start Function
- UV and OV Power Good Output
- Built-in UV and OV Protection Function
- Built-in Over Current Protection
- Built-in Thermal Shutdown Function
- Thermally Enhanced 3mm×3mm DFN Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



## **Typical Applications Circuit**



Note 4: When using a single power supply for  $V_{CC}$  and  $V_{IN}$ , a  $4.7\Omega$  resistor should be placed between them for noise isolation.

Component	Value	Unit.	Component	Value	Unit
Cvcc	1	μF	Cin	44	μF
$R_{PG}$	10	kΩ	Своот	0.1	μF
R <sub>FB2</sub>	TBD	kΩ	L1	1.5	μН
R <sub>FB1</sub>	TBD	kΩ	C <sub>OUT</sub>	88	μF

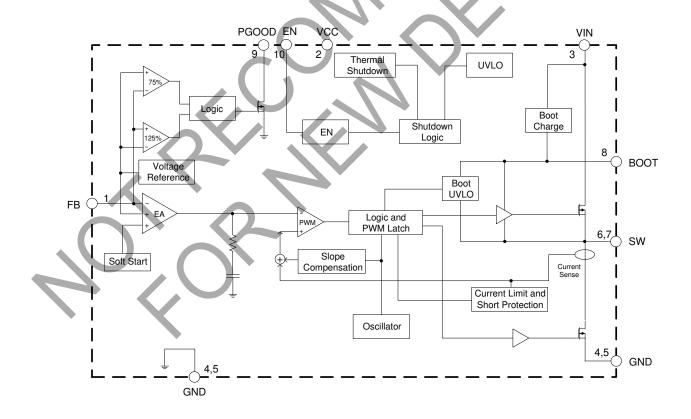
Table 1. Component Guide



## **Pin Descriptions**

Pin Number	Pin Name	Function
1	FB	Voltage Feedback Input. Connect to V <sub>OUT</sub> through a voltage divider to set the output voltage
2	VCC	Analog Power Input
3	VIN	Power Input
4, 5	GND	Ground. Must be Connected to GND on PCB
6, 7	SW	Power Switch Output
8	BOOT	High Side Switch Driver Supply
9	PGOOD	Open Drain Power Good Output
10	EN	Enable
11	Exposed Pad	Thermal Connection to the PCB. Must be connected to GND on PCB

## **Functional Block Diagram**



AP3436/A

## **Absolute Maximum Ratings** (Note 5)

Symbol	Parameter	Rating	Unit
V <sub>CC</sub> , V <sub>IN</sub>	VCC, VIN Pin Voltage	-0.3 to 6	V
V <sub>EN</sub>	EN Pin Voltage	-0.3 to 6	V
V <sub>SW</sub>	SW Pin Voltage	-0.3 to V <sub>IN</sub> +0.3	V
Vsw_transient	SW Pin Transient Voltage (<50ns)	-5 to V <sub>IN</sub> +5	V
V <sub>FB</sub>	FB Pin Voltage	-0.3 to 6	V
V <sub>PGD</sub>	PGOOD Pin Voltage	-0.3 to 6	V
V <sub>BOOT_SW</sub>	BOOT to SW Voltage	0 to 6	V
ӨЈА	Thermal Resistance (Junction to Ambient, Simulation)	33	°C/W
θ <sub>JC</sub>	Thermal Resistance (Junction to Case)	3	°C/W
TJ	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
T <sub>LEAD</sub>	Lead Temperature (Soldering, 10sec)	+260	°C
V <sub>HBM</sub>	ESD (Human Body Model)	2000	V
V <sub>MM</sub>	ESD (Machine Model)	200	V

Note 5: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

## **Recommended Operating Conditions**

Symbol	Parameter	Min	Max	Unit
Vcc	Analog Input Voltage	3.0	5.5	٧
V <sub>IN</sub>	Power Input Voltage	1.3	5.5	٧
lout(MAX)	Maximum Output Current	3	-	Α
V <sub>OUT</sub>	Output Voltage	0.8	V <sub>IN</sub>	٧
TA	Operating Ambient Temperature	-40	+85	°C



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## **Electrical Characteristics** ( $V_{CC} = 5V$ , $V_{IN} = 5V$ , $T_A = +25$ °C, unless otherwise specified.)

No	Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
V <sub>IN</sub>   Power Input Voltage   −   1.3   −   5.5   V	SUPPLY VOLTAGE (VCC,	VIN PIN)								
Internal Under Voltage Lockout   Threshold for V <sub>CC</sub>   Thresho	V <sub>CC</sub>	Analog Power Input Voltage	_	3.0	_	5.5	V			
Quiescent Current   V <sub>N =</sub> 5V   -   400   -   μA   V <sub>N =</sub> 10V,   V <sub>N =</sub> 10V,   2N   V <sub>N =</sub> 5.5V,   1.3V ≤ V <sub>N ±</sub> 5.5V,   1.3V ≤ V <sub>N ±</sub> 5.5V   -   -   1   μA   V <sub>N ±</sub> 10V,   1.3V ≤ V <sub>N ±</sub> 5.5V   -   -   1   μA   V <sub>N ±</sub> 10V,   1.3V ≤ V <sub>N ±</sub> 5.5V   -   -   1   μA   V <sub>N ±</sub> 10V,   1.3V ≤ V <sub>N ±</sub> 5.5V   -   -   1.5V   V   V <sub>N ±</sub> 10V,   1.3V ≤ V <sub>N ±</sub> 5.5V   -   -   1.5V   V   V <sub>N ±</sub> 10V,   1.3V ≤ V <sub>N ±</sub> 5.5V   -   -   1.5V   V   V <sub>N ±</sub> 10V,   1.3V ≤	V <sub>IN</sub>	Power Input Voltage	_	1.3	-	5.5	V			
Note	IQ	Quiescent Current		-	400	-	μΑ			
Nunco   Internal Under Voltage Lockout   Threshold for V <sub>CC</sub>   Threshold for V <sub>CC</sub>   Internal Under Voltage Hysteresis   C   C   T   T   T   T   T   T   T   T	Ishdn	Shutdown Supply Current	$3.0V \le V_{CC} \le 5.5V$ ,	1		1	μΑ			
VUVLO         Threshold for V <sub>CC</sub> -         2.76         2.85         V           V <sub>HYS_VCC</sub> Internal Under Voltage Hysteresis for V <sub>CC</sub> -         -         150         -         mV           VOLTAGE REFERENCE (FB PIN)           V <sub>FB</sub> Voltage Reference         3.0V ≤ V <sub>CC</sub> ≤ 5.5V         0.591         0.600         0.609         V           INTERNAL PWM FREQUENCY           MoSFET SPEC           WBOST SW = 5.0V         1.0         1.25         1.5         MHz           MIgh Side Switch On-resistance         VBOOT SW = 5.0V         -         50         100         mΩ           VBOOT_SW = 3.0V         -         50         100         mΩ           V <sub>CC</sub> = 3.0V         -         50         100         mΩ           CURRENT LIMIT           ILIMIT         Current Limit Threshold         -         4.8         7.6         -         A           TERMAL SHUTDOWN           Termal Shutdown         -         -         +160         -         °C           BOOT SPEC (BOOT PIN)           C         -	POWER ON RESET									
VHYS, VCC         for V <sub>CC</sub> —         —         150         —         mV           VOLTAGE REFERENCE (FB PIN)           VFB         Voltage Reference         3.0V ≤ V <sub>CC</sub> ≤ 5.5V         0.591         0.600         0.609         V           INTERNAL PWM FREQUENCY           MOSFET SPEC           MOSFET SPEC           VBOOT SW = 5.0V         —         50         100         mΩ           RON_L         High Side Switch On-resistance         VBOOT SW = 5.0V         —         50         100         mΩ           CURRENT LIMIT           Low Side Switch On-resistance         V <sub>CC</sub> = 5.0V         —         50         100         mΩ           CURRENT LIMIT         Current Limit Threshold         —         4.8         7.6         —         A           THERMAL SHUTDOWN         —         4.8         7.6         —         A           THERMAL SHUTDOWN         —         +160         —         °C           BOOT SPEC (BOOT PIN)           RBOOT Charge Resistor         V <sub>CC</sub> = 5.0V         —         16         —         Ω	V <sub>UVLO</sub>	_	-		2.75	2.85	V			
VFB         Voltage Reference         3.0V ≤ V <sub>CC</sub> ≤ 5.5V         0.591         0.600         0.609         V           INTERNAL PWM FREQUENCY           f         PWM Frequency         3.0V ≤ V <sub>CC</sub> ≤ 5.5V         1.0         1.25         1.5         MHz           MOSFET SPEC           RON_H         High Side Switch On-resistance         V <sub>BOOT_SW</sub> = 5.0V         -         50         100         mΩ           V <sub>BOOT_SW</sub> = 3.0V         -         50         100         mΩ           V <sub>CC</sub> = 5.0V         -         50         100         mΩ           CURRENT LIMIT         Current Limit Threshold         -         4.8         7.6         -         A           THERMAL SHUTDOWN           Type Current Limit Threshold         -         4.8         7.6         -         A           Type Current Limit Threshold         -         -         4.8         7.6         -         A           Thermal Shutdown         -         -         4.8         7.6         -         A           Thermal Shutdown         -         -         +160         -         °C <t< td=""><td>V<sub>HYS_</sub>vcc</td><td></td><td>-</td><td>-</td><td>150</td><td>-</td><td>mV</td></t<>	V <sub>HYS_</sub> vcc		-	-	150	-	mV			
NTERNAL PWM FREQUENCY   3.0V ≤ V <sub>CC</sub> ≤ 5.5V   1.0   1.25   1.5   MHz	VOLTAGE REFERENCE (F	B PIN)								
f         PWM Frequency         3.0V ≤ V <sub>CC</sub> ≤ 5.5V         1.0         1.25         1.5         MHz           MOSFET SPEC           PRON_H         High Side Switch On-resistance         VBOOT SW = 5.0V         -         50         100         mΩ           VBOOT SW = 3.0V         -         70         140         mΩ           CURRENT LIMIT           ILIMIT         Current Limit Threshold         -         4.8         7.6         -         A           THERMAL SHUTDOWN           TTSD         Thermal Shutdown         -         -         +160         -         °C           -         Hysteresis         -         -         +20         -         °C           BOOT SPEC (BOOT PIN)           -         BOOT Charge Resistor         VCC = 5.0V         -         16         -         Ω           -         BOOT Charge Resistor         VCC = 3.0V         -         16         -         V	$V_{FB}$	Voltage Reference	3.0V ≤ V <sub>CC</sub> ≤ 5.5V	0.591	0.600	0.609	V			
MOSFET SPEC           RON_H         High Side Switch On-resistance         VBOOT, SW = 5.0V         -         50         100         mΩ           RON_L         Low Side Switch On-resistance $V_{CC} = 3.0V$ -         50         100         mΩ           CURRENT LIMIT         Current Limit Threshold         -         4.8         7.6         -         A           THERMAL SHUTDOWN         -         -         4.8         7.6         -         A           TTSD         Thermal Shutdown         -         -         +160         -         °C           -         Hysteresis         -         -         +20         -         °C           BOOT SPEC (BOOT PIN)         BOOT Charge Resistor         VCC = 5.0V         -         16         -         Ω           -         BOOT to SW UVLO         VCC = 3.0V         -         16         -         Q	INTERNAL PWM FREQUENCY									
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	f	PWM Frequency	3.0V ≤ V <sub>CC</sub> ≤ 5.5V	1.0	1.25	1.5	MHz			
RON_H         High Side Switch On-resistance         V <sub>BOOT_SW</sub> = 3.0V         -         70         140         mΩ           RON_L         Low Side Switch On-resistance         V <sub>CC</sub> = 5.0V         -         50         100         mΩ           CURRENT LIMIT           I <sub>LIMIT</sub> Current Limit Threshold         -         4.8         7.6         -         A           THERMAL SHUTDOWN           T <sub>TSD</sub> Thermal Shutdown         -         -         +160         -         °C           -         Hysteresis         -         -         +20         -         °C           BOOT SPEC (BOOT PIN)           R <sub>BOOT</sub> BOOT Charge Resistor         V <sub>CC</sub> = 5.0V         -         16         -         Ω           -         BOOT to SW UVLO         V <sub>CC</sub> = 3.0V         -         2.2         -         V	MOSFET SPEC	MOSFET SPEC								
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	Pa	High Side Switch On recietance	V <sub>BOOT</sub> _sw = 5.0V	-	50	100	mΩ			
CURRENT LIMIT           I <sub>LIMIT</sub> Current Limit Threshold         -         4.8         7.6         -         A           THERMAL SHUTDOWN           T <sub>TSD</sub> Thermal Shutdown         -         -         +160         -         °C           -         Hysteresis         -         -         +20         -         °C           BOOT SPEC (BOOT PIN)         -         16         -         Ω           -         BOOT to SW UVLO         V <sub>CC</sub> = 3.0V         -         16         -         Ω	non_H	High Side Switch On-resistance	$V_{BOOT\_SW} = 3.0V$	-	70	140	mΩ			
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Day.	Low Side Switch On registered	V <sub>CC</sub> = 5.0V	-	50	100	mΩ			
I <sub>LIMIT</sub> Current Limit Threshold         -         4.8         7.6         -         A           THERMAL SHUTDOWN           T <sub>TSD</sub> Thermal Shutdown         -         -         +160         -         °C           -         Hysteresis         -         -         +20         -         °C           BOOT SPEC (BOOT PIN)         -         -         16         -         Ω           -         BOOT Charge Resistor         V <sub>CC</sub> = 5.0V         -         16         -         Ω           -         BOOT to SW UVLO         V <sub>CC</sub> = 3.0V         -         2.2         -         V	HON_L	Low Side Switch On-resistance	V <sub>CC</sub> = 3.0V	_	70	140	mΩ			
THERMAL SHUTDOWN           T <sub>TSD</sub> Thermal Shutdown         -         -         +160         -         °C           -         Hysteresis         -         -         +20         -         °C           BOOT SPEC (BOOT PIN)         -         +20         -         °C           R <sub>BOOT</sub> BOOT Charge Resistor         V <sub>CC</sub> = 5.0V         -         16         -         Ω           -         BOOT to SW UVLO         V <sub>CC</sub> = 3.0V         -         2.2         -         V	CURRENT LIMIT									
TrsD         Thermal Shutdown         -         -         +160         -         °C           -         Hysteresis         -         -         +20         -         °C           BOOT SPEC (BOOT PIN)           RBOOT         BOOT Charge Resistor         V <sub>CC</sub> = 5.0V         -         16         -         Ω           -         BOOT to SW UVLO         V <sub>CC</sub> = 3.0V         -         2.2         -         V	ILIMIT	Current Limit Threshold	_	4.8	7.6	_	Α			
-       Hysteresis       -       -       +20       -       °C         BOOT SPEC (BOOT PIN)         RBOOT       BOOT Charge Resistor       V <sub>CC</sub> = 5.0V       -       16       -       Ω         -       BOOT to SW UVLO       V <sub>CC</sub> = 3.0V       -       2.2       -       V	THERMAL SHUTDOWN									
BOOT SPEC (BOOT PIN)       RBOOT     BOOT Charge Resistor $V_{CC} = 5.0V$ -     16     - $\Omega$ -     BOOT to SW UVLO $V_{CC} = 3.0V$ -     2.2     - $V$	T <sub>TSD</sub>	Thermal Shutdown	_	-	+160	_	°C			
R <sub>BOOT</sub> BOOT Charge Resistor     V <sub>CC</sub> = 5.0V     -     16     -     Ω       -     BOOT to SW UVLO     V <sub>CC</sub> = 3.0V     -     2.2     -     V	_	Hysteresis	_	ı	+20	1	°C			
- BOOT to SW UVLO V <sub>CC</sub> = 3.0V - 2.2 - V	BOOT SPEC (BOOT PIN)									
	R <sub>ВООТ</sub>	BOOT Charge Resistor	V <sub>CC</sub> = 5.0V	_	16	_	Ω			
COFT CTART	_	BOOT to SW UVLO	V <sub>CC</sub> = 3.0V	_	2.2	_	V			
SUFFSTART	SOFT START									
t <sub>SS</sub> Soft Start Time – 0.8 – 2 ms	tss	Soft Start Time	_	0.8	_	2	ms			



AP3436/A

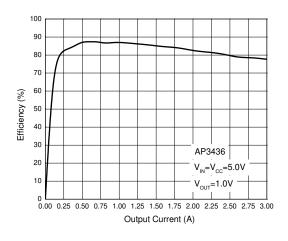
## **Electrical Characteristics** (Cont. $V_{CC} = 5V$ , $V_{IN} = 5V$ , $T_A = +25$ °C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
ENABLE (EN PIN)							
V <sub>EN_L</sub>	EN D. T. J. J.	-	_	-	0.8	V	
V <sub>EN_H</sub>	EN Pin Threshold	_	1.6	- (	_	V	
POWER GOOD (PGOOD P	·IN)						
		V <sub>FB</sub> falling (Fault) 70		75	-		
V		V <sub>FB</sub> rising (Good)	77	82	-	0/1/	
V <sub>FВТН</sub>	Feedback Threshold	V <sub>FB</sub> rising (Fault)	-	125	130	%V <sub>REF</sub>	
		V <sub>FB</sub> falling (Good)		118	123		
tpg_dly	Delay Time for PGOOD from High to Low	-	1	30	1	μs	
R <sub>PG</sub>	Internal Power Good Pull Low Resistance	-	-		150	Ω	
R <sub>PG_UP</sub>	External Pull-up Resistance Range		3000	-	_	Ω	
SYSTEM PERFORMANCE							
V <sub>UVP</sub>	Output Under Voltage Protection Threshold	V <sub>IN</sub> = 1.3 to 5.5V	<b>/</b> -	-	0.5× V <sub>OUT</sub>	V	
t <sub>UVP</sub>	Delay Time for UVP Triggered	V <sub>IN</sub> = 1.5 to 5V	_	65	-	μs	
V <sub>OVP</sub>	Output Over Voltage Protection Threshold	V <sub>IN</sub> = 1.3 to 5.5V	1.5× V <sub>OUT</sub>	ı	ı	V	
t <sub>OVP</sub>	Delay Time for OVP Triggered	V <sub>IN</sub> = 1.5 to 5V	-	65	-	μs	
I <sub>OUT</sub>	Output Current	$V_{IN} = 1.5 \text{ to } 5V,$ $V_{OUT} = 1.0V$	3	-	-	Α	
-	Output Voltage Line Regulation	V <sub>IN</sub> = 1.5 to 5V, I <sub>OUT</sub> = 100mA	_	0.4	-	%× V <sub>OUT</sub> /V	
- /	Output Voltage Load Regulation	I <sub>OUT</sub> = 0A to 3A	_	0.3	_	%× V <sub>OUT</sub> /A	
VTRAN	Output Voltage Load Transient	$V_{IN} = 5V$ , $V_{OUT} = 1.0V$ , $dI/dt = 400mA/\mu s$	_	±2.5	_	%× V <sub>OUT</sub> /A	
η	Efficiency	V <sub>CC</sub> = 5V, V <sub>IN</sub> =5V, I <sub>OUT</sub> = 3A, V <sub>OUT</sub> = 1.2V	_	80	_	%	

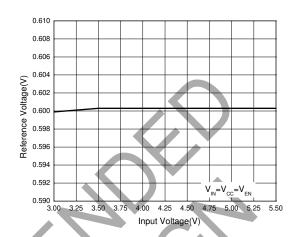


### **Performance Characteristics**

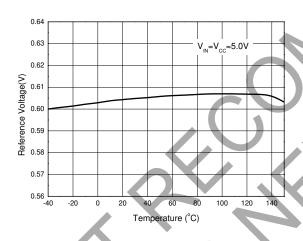
### **Efficiency vs. Output Current**



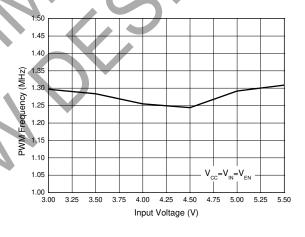
### Reference Voltage vs. Input Voltage



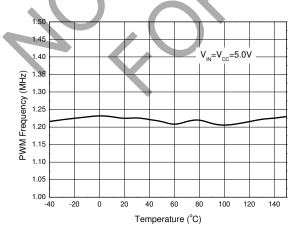
### Reference Voltage vs. Temperature



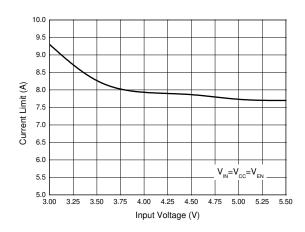
**PWM Frequency vs. Input Voltage** 



### **PWM Frequency vs. Temperature**



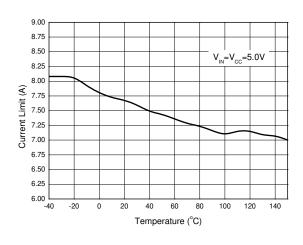
### **Current Limit vs. Input Voltage**



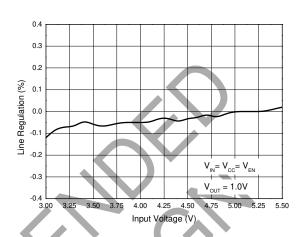


## **Performance Characteristics (Cont.)**

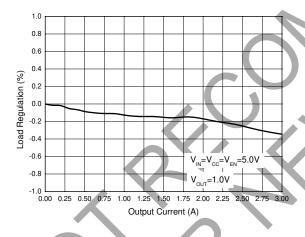
### **Current Limit vs. Temperature**



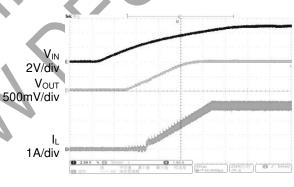
### Line Regulation vs. Input Voltage



### Load Regulation vs. Output Current

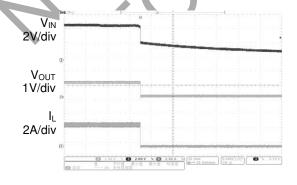


Power on Waveform (V<sub>IN</sub>=V<sub>CC</sub>=5V, V<sub>OUT</sub>=1V, I<sub>OUT</sub>=3A)

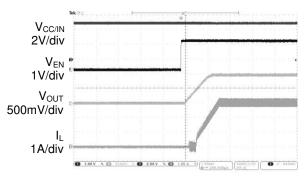


Time 400µs/div

# Power off Waveform (V<sub>IN</sub>=V<sub>CC</sub>=5V, V<sub>OUT</sub>=1V, I<sub>OUT</sub>=3A)



# Enable Waveform (V<sub>IN</sub>=V<sub>CC</sub>=5V, V<sub>OUT</sub>=1V, I<sub>OUT</sub>=3A)

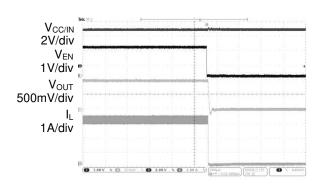


Time 1ms/div



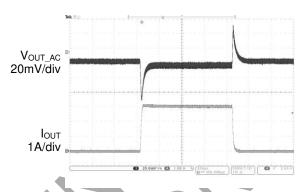
## **Performance Characteristics (Cont.)**

### 



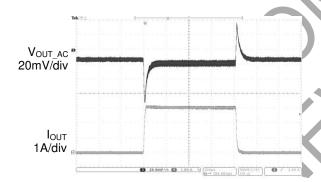
Time 200µs/div

# Load Transient Response ( $V_{IN}$ = $V_{CC}$ =5V, $V_{OUT}$ =1V, $I_{OUT}$ =0 to 3A)



Time 200µs/div

# Load Transient Response (V<sub>IN</sub>=V<sub>CC</sub>=3.3V, V<sub>OUT</sub>=1V, I<sub>OUT</sub>=0 to 3A)



Time 200µs/div

AP3436/A

### **Application Information**

#### 1. Overview

The AP3436/A is a 3A synchronous buck (step-down) converter with two integrated N-channel MOSFETs. For AP3436, the regulator operates in PWM mode with 1.25MHz switching frequency internally, regardless of if the load current is high or low. For AP3436A, when the load is very light, the regulator automatically operates in the PSM mode to minimize the switching loss, thus achieving high efficiency at light load. When the load increases, the regulator automatically switches over to a current-mode PWM operating at nominal 1.25MHz switching frequency.

#### 2. Power On Reset

A Power On Reset (POR) circuitry continuously monitors the supply voltage at VCC pin. Once the rising POR threshold is exceeded, the AP3436/A sets itself to active state and is ready to accept chip enable command. The rising POR threshold is typically 2.75V.

#### 3. Soft Start

A built-in soft-start is used to prevent surge current from power supply input  $V_{IN}$  during turn on (Referring to the Functional Block Diagram). The error amplifier is a three-input device. Reference voltage  $V_{REF}$  or the internal soft-start voltage  $V_{SS}$  whichever is smaller dominates the behavior of the non-inverting inputs of the error amplifier.  $V_{SS}$  internally ramps up to 0.6V after the soft-start cycle is initiated. The ramp is created digitally, so the output voltage will follow the  $V_{SS}$  signal and ramps up smoothly to its target level.

#### 4. EN Function

The AP3436/A provides Enable Function. Pulling this pin higher than 1.6V statically enables the AP3436/A while pulling the pin lower than 0.8V statically for longer than  $10\mu s$  will shutdown the IC.

#### 5. Adjusting Output Voltage

The output voltage is set with a resistor divider from the FB pin. It is recommended to use divider resistors with 1% tolerance or better. Start with a  $100k\Omega$  for the resistor R1 and use the following equation to calculate R2. Consider using larger value resistors to improve efficiency at very light loads. If the values are too high, the regulator is more susceptible to noise and the voltage errors caused by FB input current are noticeable.

$$R2 = \frac{R1 \times 0.6}{V_{OUT} - 0.6}$$

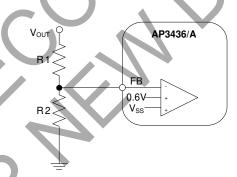


Figure 1. Voltage Divider Circuit

### 6. Short Circuit Protection (SCP)

The AP3436/A has Over Current Protection (OCP) and Under Voltage Protection (UVP) functions.

### 6.1 OCP Function

The high side switch current is detected during each cycle. During SCP conditions, the output voltage is pulled down and the switch current is increased. Once the increased high side switching current is detected to trigger the current limit of high side switch, the high side switch will be immediately turned off and will not be turned on again until the next switching cycle. When over current condition is removed, the AP3436/A will recover back to normal operation again.

#### 6.2 UVP Function

The FB voltage is also monitored for Under Voltage Protection. The UV threshold is set at 0.2V. The under voltage protection has 65µs triggered delay. When UVP is triggered, both high side and low side are shutdown immediately. The UVP is a latched function, reset power supply or EN pin to restart AP3436/A again.



AP3436/A

### **Application Information (Cont.)**

### 7. Over Voltage Protection (OVP)

The output voltage is continuously monitored for Over Voltage Protection by FB pin. When it is larger than 1.67 times as setting, the OVP function is triggered. The Over Voltage Protection has 65µs triggered delay.

When OVP is triggered, both high side and low side are shutdown immediately and the output voltage is discharged by an internal  $1k\Omega$  resistor.

#### 8. Power Good

The PGOOD pin output connects an open drain MOSFET. The output is pulled low when the FB voltage enters the fault condition by falling below 75% or rising above 125% of the nominal internal reference voltage. There is a 7% hysteresis on the threshold voltage, so when the FB voltage rises to the good condition above 82% or falls below 118% of the internal voltage reference the PGOOD output MOSFET is turned off. It is recommended to use a pull-up resistor between the values of  $3k\Omega$  and  $100k\Omega$  to a voltage source that is 5V or less.

#### 9. Thermal Shutdown

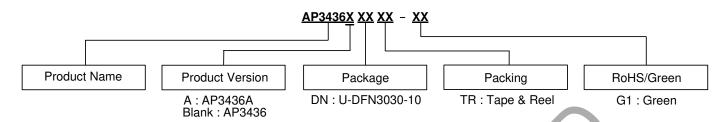
The device implements an internal thermal shutdown to protect itself if the junction temperature exceeds +160°C. Switching is stopped when the junction temperature exceeds the thermal trip threshold. Once the die temperature decreases below +140°C, the device reinitiates the soft start operation. The thermal shutdown hysteresis is +20°C.



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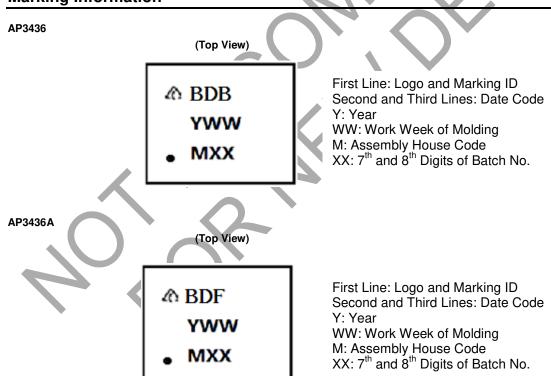


## **Ordering Information**



Package	Temperature Range	Function	Part Number	Marking ID	Packing
LL DEN2020 10	40 to 1959C	PWM	AP3436DNTR-G1	BDB	5000/Tape & Reel
U-DFN3030-10	-40 to +85°C	PWM/PSM	AP3436ADNTR-G1	BDF	5000/Tape & Reel

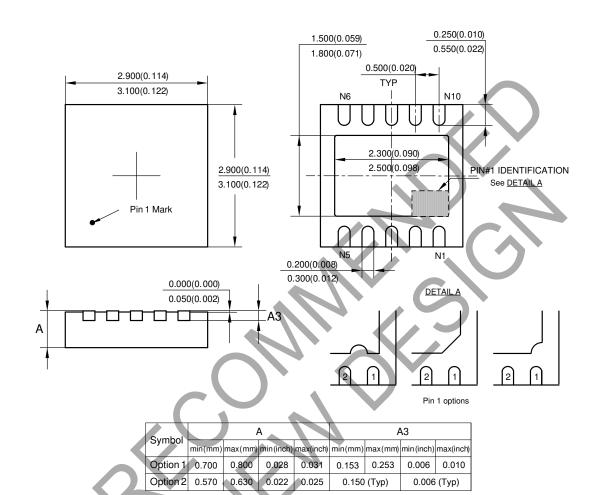
## **Marking Information**





## Package Outline Dimensions (All dimensions in mm(inch).)

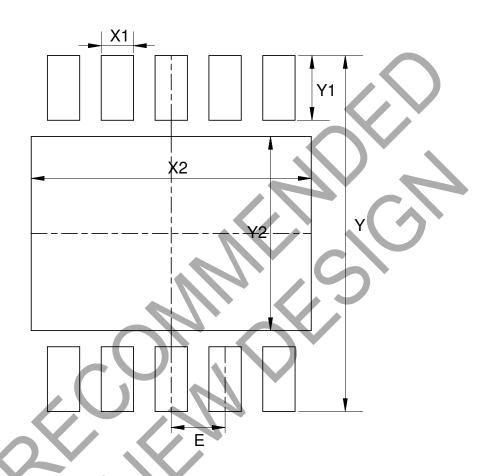
### (1) Package Type: U-DFN3030-10





## **Suggested Pad Layout**

## (1) Package Type: U-DFN3030-10



Dimensions	Y	X1	Y1	X2	Y2	E
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	3.300/0.130	0.300/0.012	0.600/0.024	2.600/0.102	1.800/0.071	0.500/0.020



AP3436/A

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